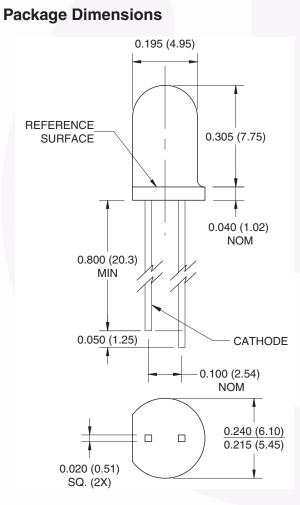
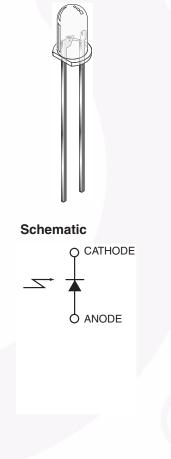


QSD2030 Plastic Silicon Photodiode

Features

- PIN photodiode
- Package type: T-1 3/4 (5mm lens diameter)
- Wide reception angle, 40°
- Package material and color: clear epoxy
- High sensitivity
- Peak sensitivity $\lambda = 880$ nm
- Radiant sensitive area: 1mm x 1mm





Notes:

- 1. Dimensions for all drawings are in inches (mm).
- 2. Tolerance of ± 0.010 (0.25) on all non-nominal dimensions unless otherwise specified.

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Absolute Maximum Ratings (T_A = 25°C unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

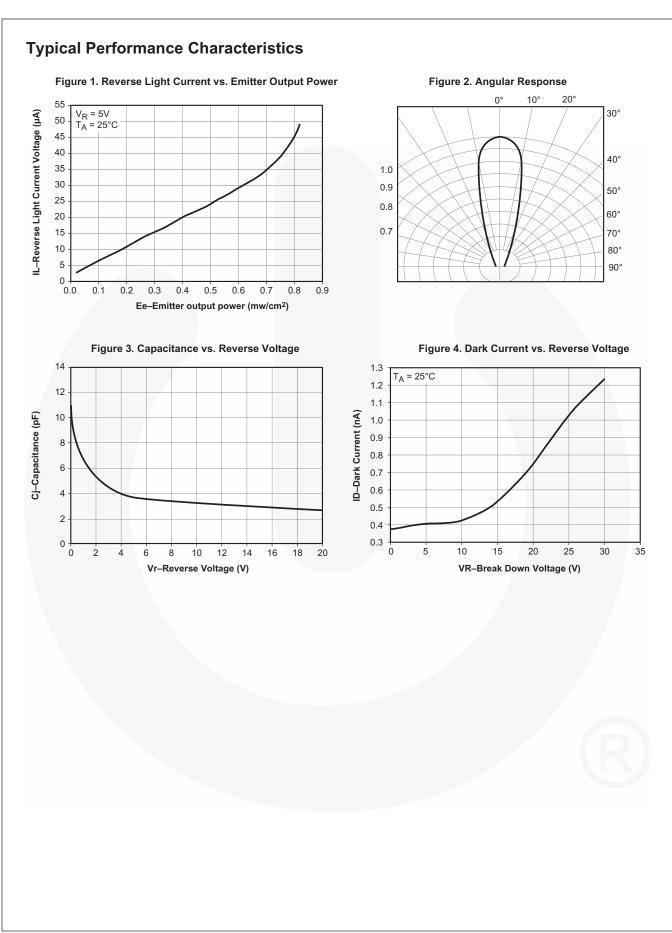
Symbol	Parameter	Rating	Unit
T _{OPR}	Operating Temperature	-40 to +100	°C
T _{STG}	Storage Temperature	-40 to +100	°C
T _{SOL-I}	Soldering Temperature (Iron) ^(2,3,4)	240 for 5 sec	°C
T _{SOL-F}	Soldering Temperature (Flow) ^(2,3)	260 for 10 sec	°C
V _{BR}	Reverse Breakdown Voltage	50	V
PD	Power Dissipation ⁽¹⁾	100	mW

Notes:

- 1. Derate power dissipation linearly 1.33mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6mm) minimum from housing.

Electrical/Optical Characteristics (T_A =25°C)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
λ_{PS}	Peak Sensitivity Wavelength			880		nm
λ_{SR}	Wavelength Sensitivity Range		400		1100	nm
Θ	Reception Angle			±20		0
V _F	Forward Voltage	I _F = 80mA		1.3		V
Ι _D	Reverse Dark Current	V _R = 10V, Ee = 0			10	nA
ΙL	Reverse Light Current	Ee = 0.5mW/cm ² , V _R = 5V, λ = 950nm	15	25		μA
С	Capacitance	V _R = 0, f = 1MHz, Ee = 0		60		pF
t _r	Rise Time	$V_{R} = 5V, R_{L} = 50\Omega, \lambda = 950nm$		5		ns
t _f	Fall Time			5		



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